

CSD17556Q5B 30-V N-Channel NexFET™ Power MOSFET

1 Features

- Extremely Low Resistance
- Ultra-Low Q_g and Q_{gd}
- Low-Thermal Resistance
- Avalanche Rated
- Lead-Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm x 6-mm Plastic Package

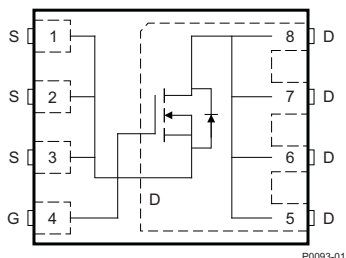
2 Applications

- Point of Load Synchronous Buck in Networking, Telecom, and Computing Systems
- Synchronous Rectification
- Active ORing and Hotswap Applications

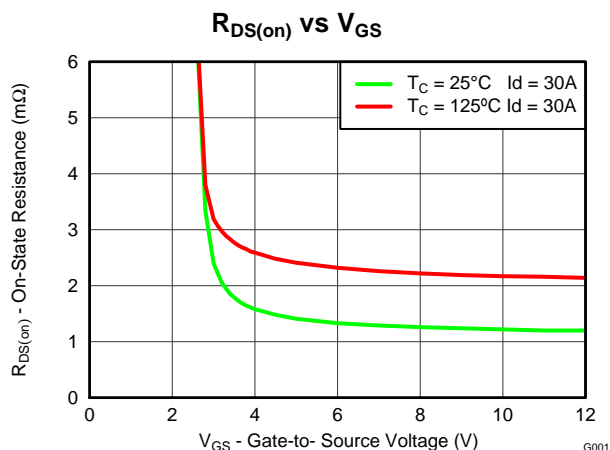
3 Description

This 30-V, 1.2-m Ω , 5-mm x 6-mm NexFET™ power MOSFET is designed to minimize losses in synchronous rectification and other power conversion applications.

Top View



P0093-01



Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	30		V
Q_g	Gate Charge Total (4.5 V)	30		nC
Q_{gd}	Gate Charge Gate-to-Drain	7.5		nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = 4.5\text{ V}$	1.5	m Ω
		$V_{GS} = 10\text{ V}$	1.2	
$V_{GS(th)}$	Threshold Voltage	1.4		V

Device Information⁽¹⁾

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD17556Q5B	2500	13-Inch Reel	SON	Tape and Reel
CSD17556Q5BT	250		5.00-mm x 6.00-mm Plastic Package	

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	30	V
V_{GS}	Gate-to-Source Voltage	± 20	V
I_D	Continuous Drain Current (Package Limited)	100	A
	Continuous Drain Current (Silicon Limited), $T_C = 25^\circ\text{C}$	215	
	Continuous Drain Current ⁽¹⁾	34	
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽¹⁾⁽²⁾	400	A
P_D	Power Dissipation ⁽¹⁾	3.1	W
	Power Dissipation, $T_C = 25^\circ\text{C}$	191	
T_J , T_{stg}	Operating Junction, Storage Temperature	-55 to 150	$^\circ\text{C}$
E_{AS}	Avalanche Energy, Single Pulse $I_D = 100\text{ A}$, $L = 0.1\text{ mH}$, $R_G = 25\ \Omega$	500	mJ

(1) Typical $R_{\theta JA} = 40^\circ\text{C}/\text{W}$ on 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Max $R_{\theta JC} = 1.3^\circ\text{C}/\text{W}$, pulse duration $\leq 100\ \mu\text{s}$, duty cycle $\leq 1\%$.

Gate Charge

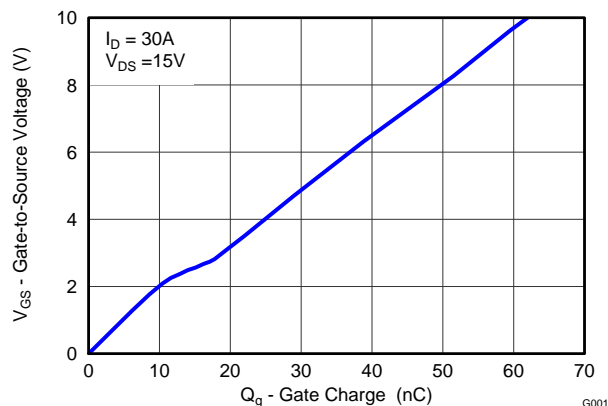


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4 Revision History

Changes from Revision C (January 2017) to Revision D Page

- Corrected front page formatting error..... **1**

Changes from Revision B (August 2014) to Revision C Page

- Changed part numbers in the *Device Information* table..... **1**
- Added *Receiving Notification of Documentation Updates* section and *Community Resources* section to the *Device and Documentation Support* section

Changes from Revision A (October 2013) to Revision B Page

- Increased max pulsed drain current to 400 A. **1**
- Updated pulsed drain current conditions
- Updated [Figure 1](#) to a normalized $R_{\theta JC}$ curve
- Updated the SOA in [Figure 10](#)
- Updated the mechanical drawing and dimensions table to show previously unknown dimensions

Changes from Original (March 2013) to Revision A Page

- Updated the dimensions table in the Mechanical Data Section to include DIM "H" values

5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^\circ\text{C}$ (unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV_{DSS}	Drain-to-source voltage	$V_{GS} = 0\text{ V}, I_{DS} = 250\ \mu\text{A}$	30			V
I_{DSS}	Drain-to-source leakage current	$V_{GS} = 0\text{ V}, V_{DS} = 24\text{ V}$			1	μA
I_{GSS}	Gate-to-source leakage current	$V_{DS} = 0\text{ V}, V_{GS} = 20\text{ V}$			100	nA
$V_{GS(th)}$	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_{DS} = 250\ \mu\text{A}$	1.15	1.4	1.65	V
$R_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 4.5\text{ V}, I_{DS} = 40\text{ A}$		1.5	1.8	m Ω
		$V_{GS} = 10\text{ V}, I_{DS} = 40\text{ A}$		1.2	1.4	
g_{fs}	Transconductance	$V_{DS} = 15\text{ V}, I_{DS} = 40\text{ A}$		197		S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 15\text{ V},$ $f = 1\text{ MHz}$		5400	7020	pF
C_{oss}	Output capacitance			1770	2310	pF
C_{rss}	Reverse transfer capacitance			68	88	pF
R_G	Series gate resistance			0.7	1.4	Ω
Q_g	Gate charge total (4.5 V)	$V_{DS} = 15\text{ V}, I_{DS} = 40\text{ A}$		30	39	nC
Q_{gd}	Gate charge gate-to-drain			7.5		nC
Q_{gs}	Gate charge gate-to-source			11		nC
$Q_{g(th)}$	Gate charge at V_{th}			6.1		nC
Q_{oss}	Output charge	$V_{DS} = 15\text{ V}, V_{GS} = 0\text{ V}$		48		nC
$t_{d(on)}$	Turnon delay time	$V_{DS} = 15\text{ V}, V_{GS} = 4.5\text{ V},$ $I_{DS} = 40\text{ A}, R_G = 2\ \Omega$		14		ns
t_r	Rise time			26		ns
$t_{d(off)}$	Turnoff delay time			27		ns
t_f	Fall time			12		ns
DIODE CHARACTERISTICS						
V_{SD}	Diode forward voltage	$I_{SD} = 40\text{ A}, V_{GS} = 0\text{ V}$		0.8	1	V
Q_{rr}	Reverse recovery charge	$V_{DD} = 15\text{ V}, I_F = 40\text{ A}, di/dt = 300\text{ A}/\mu\text{s}$		68		nC
t_{rr}	Reverse recovery time			36		ns

5.2 Thermal Information

 $T_A = 25^\circ\text{C}$ (unless otherwise stated)

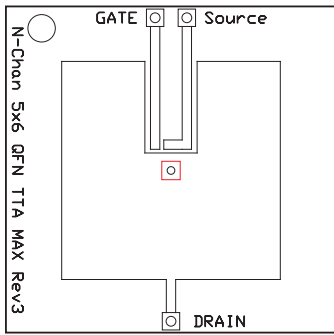
THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance ⁽¹⁾			1.3	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾			50	

- $R_{\theta JC}$ is determined with the device mounted on a 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu pad on a 1.5-in × 1.5-in (3.81-cm × 3.81-cm), 0.06-in (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
- Device mounted on FR4 material with 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu.

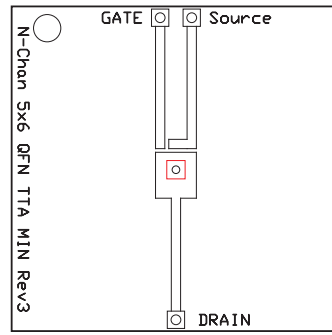
CSD17556Q5B

SLPS392D – MARCH 2013 – REVISED NOVEMBER 2017

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Max $R_{\theta JA} = 50^{\circ}\text{C/W}$
when mounted on 1-in²
(6.45-cm²) of
2-oz (0.071-mm) thick
Cu.



Max $R_{\theta JA} = 125^{\circ}\text{C/W}$
when mounted on a
minimum pad area of
2-oz (0.071-mm) thick
Cu.

5.3 Typical MOSFET Characteristics

$T_A = 25^{\circ}\text{C}$ (unless otherwise stated)

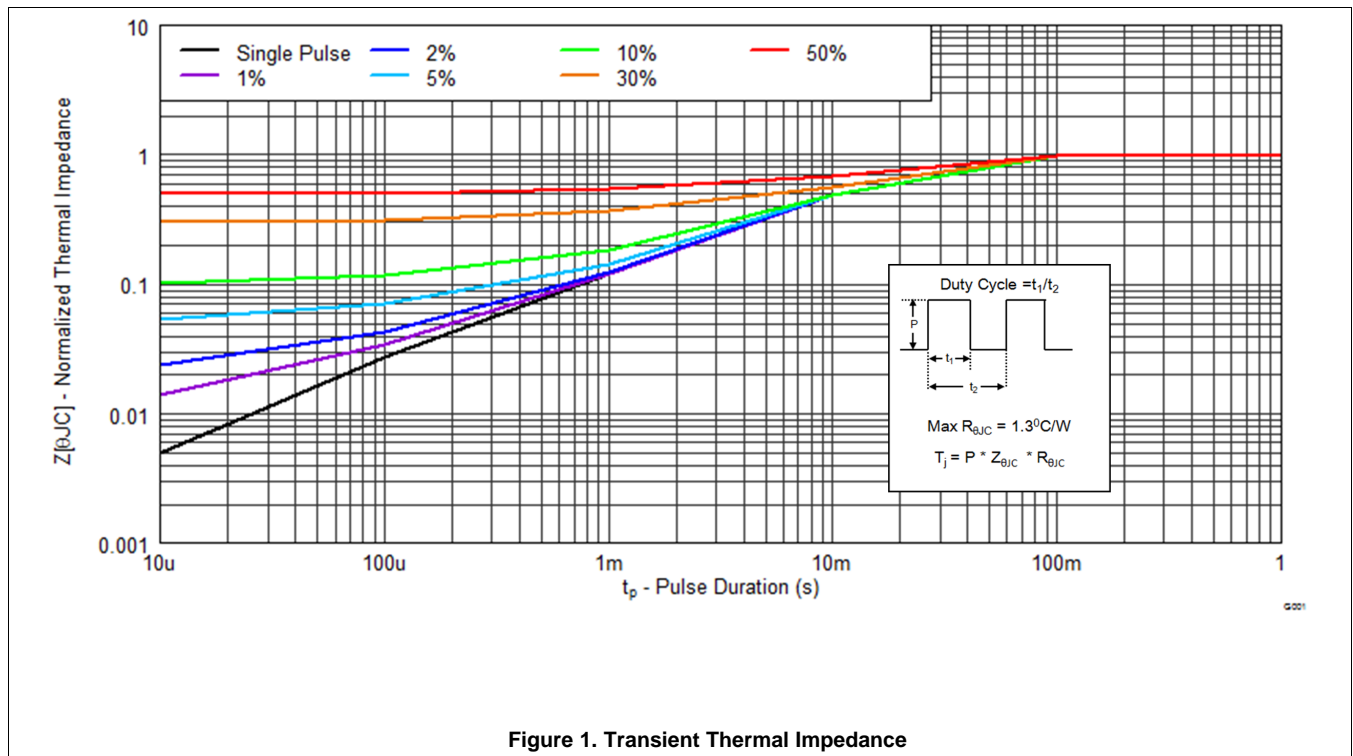


Figure 1. Transient Thermal Impedance

Typical MOSFET Characteristics (continued)

T_A = 25°C (unless otherwise stated)

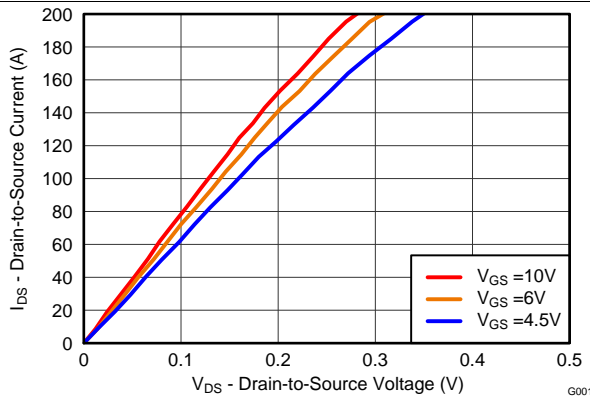


Figure 2. Saturation Characteristics

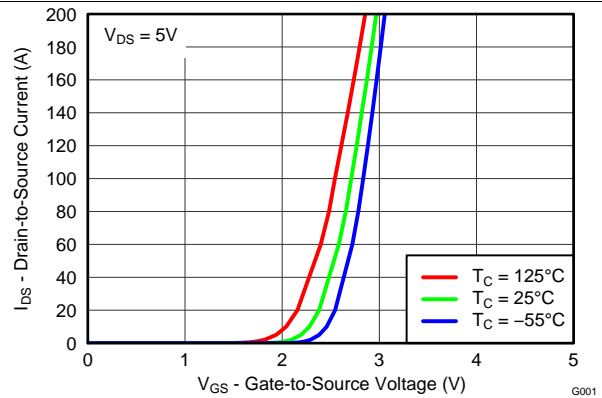


Figure 3. Transfer Characteristics

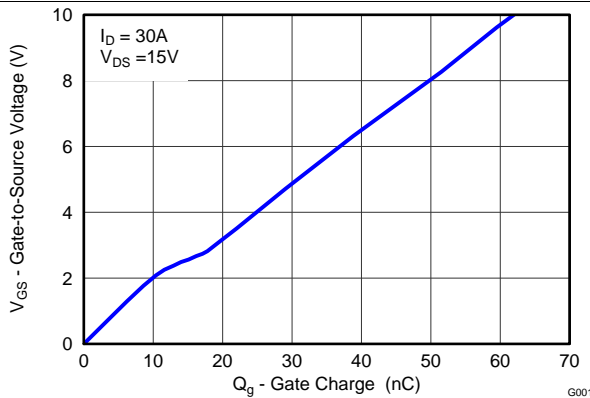


Figure 4. Gate Charge

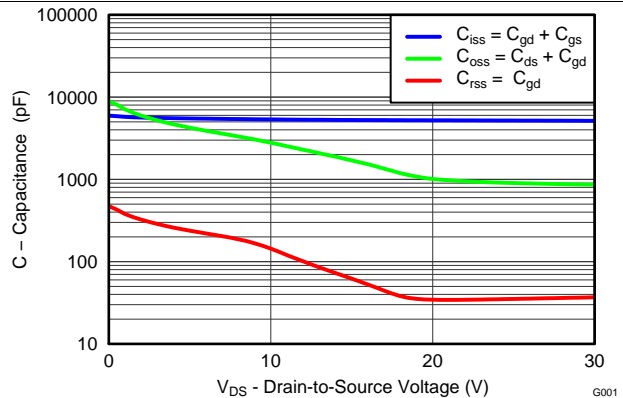


Figure 5. Capacitance

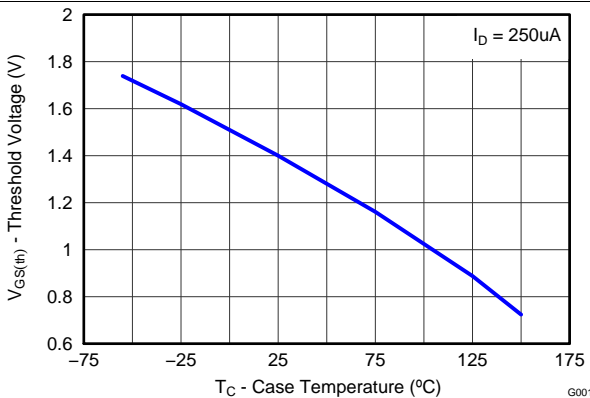


Figure 6. Threshold Voltage vs Temperature

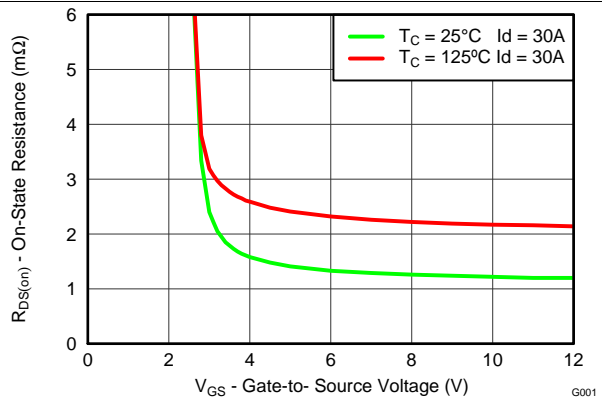


Figure 7. On-State Resistance vs Gate-to-Source Voltage

Typical MOSFET Characteristics (continued)

T_A = 25°C (unless otherwise stated)

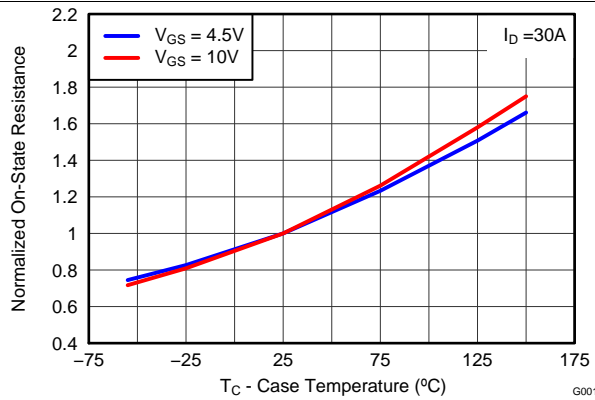


Figure 8. Normalized On-State Resistance vs Temperature

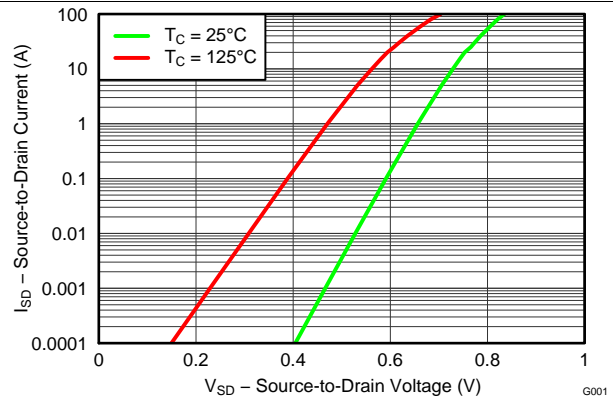


Figure 9. Typical Diode Forward Voltage

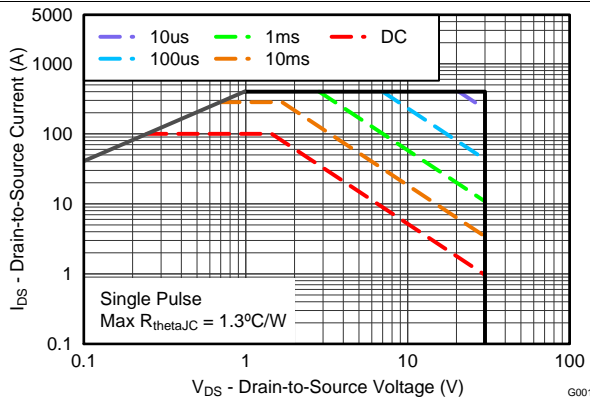


Figure 10. Maximum Safe Operating Area (SOA)

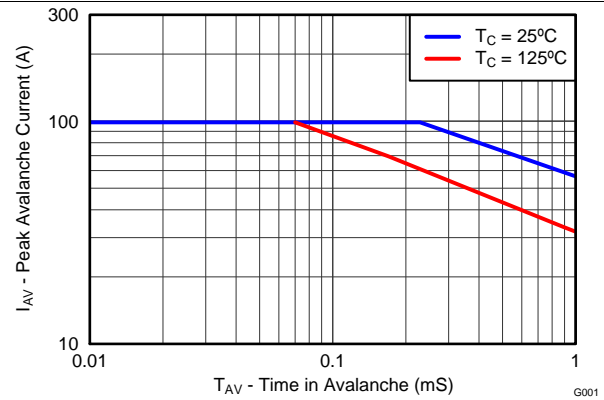


Figure 11. Single Pulse Unclamped Inductive Switching

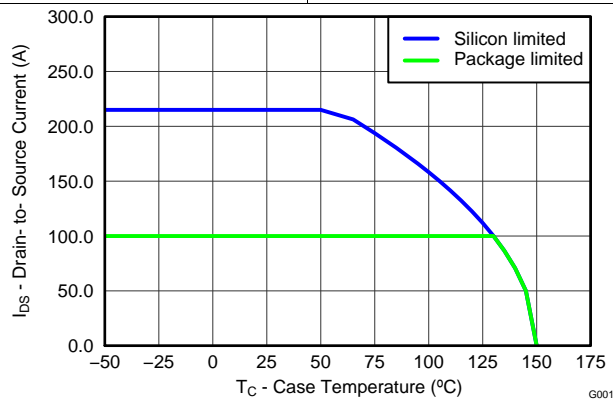


Figure 12. Maximum Drain Current vs Temperature

6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

NexFET, E2E are trademarks of Texas Instruments.
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6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

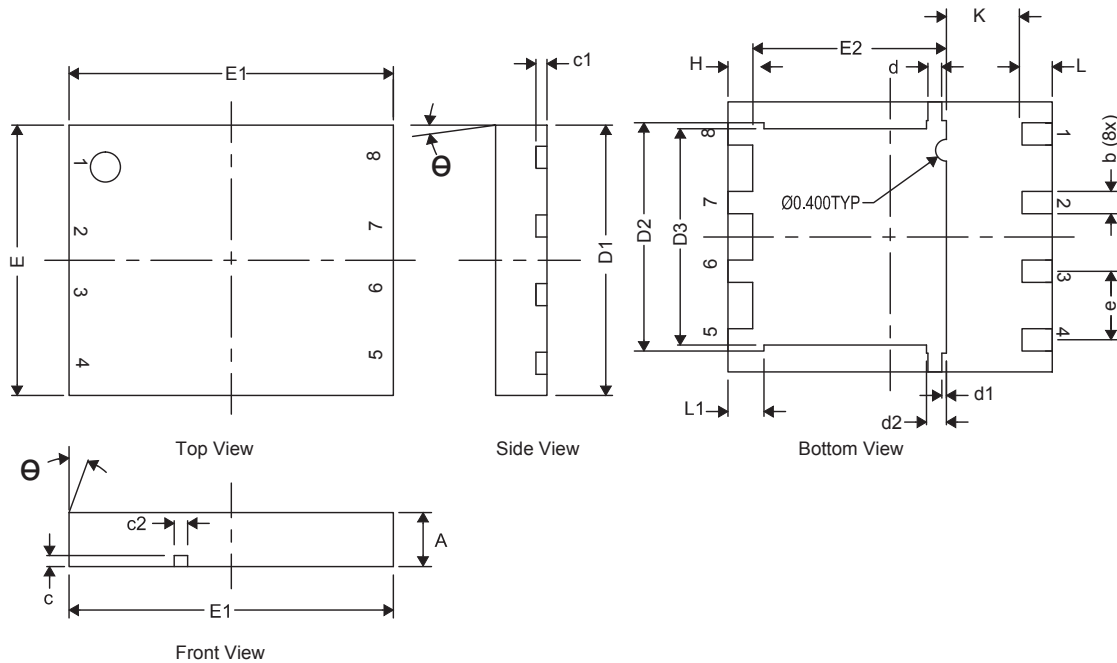
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q5B Package Dimensions



DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.80	1.00	1.05
b	0.36	0.41	0.46
c	0.15	0.20	0.25
c1	0.15	0.20	0.25
c2	0.20	0.25	0.30
D1	4.90	5.00	5.10
D2	4.12	4.22	4.32
D3	3.90	4.00	4.10
d	0.20	0.25	0.30
d1	0.085 TYP		
d2	0.319	0.369	0.419
E	4.90	5.00	5.10
E1	5.90	6.00	6.10
E2	3.48	3.58	3.68
e	1.27 TYP		
H	0.36	0.46	0.56
L	0.46	0.56	0.66
L1	0.57	0.67	0.77
θ	0°	—	—
K	1.40 TYP		

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD17556Q5B	ACTIVE	VSON-CLIP	DNK	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD17556	Samples
CSD17556Q5BT	ACTIVE	VSON-CLIP	DNK	8	250	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD17556	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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